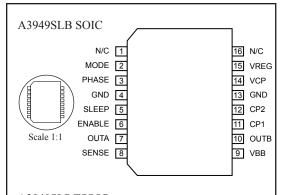
# A3949

# DMOS Full-Bridge Motor Driver



#### A3949SLP TSSOP 16 N/C MODE 15 VREG 14 VCP PHASE 13 GND GND 12 CP2 SLEEP 5 ENABLE 6 11 CP1 Scale 1:1 OUTA 7 10 оитв SENSE 8 9 VBB

#### **ABSOLUTE MAXIMUM RATINGS**

Load Supply Voltage

Load Supply Voltage	
$V_{_{\mathrm{BB}}}$	36 V
$V_{BB}$ (Peak $\leq 2 \mu s$ )	38 V
Output Current, I <sub>OUT</sub> (Repetitive) <sup>1</sup>	
Sense Voltage, V <sub>SENSE</sub>	0.5 V
Logic Input Voltage, V <sub>IN</sub>	0.3 V to 7 V
Package Power Dissipation, P <sub>D</sub>	
A3949SLB <sup>2</sup>	52°C / W
A3949SLP <sup>3</sup>	34°C / W
Operating Temperature Range	

Junction Temperature, T<sub>J</sub> ......+150°C Max. Storage Temperature, T<sub>S</sub>.....-55°C to +150°C ¹Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of

Ambient Temperature, T<sub>A</sub> .....-20°C to +85°C

conditions, DO NOT exceed the specified  $I_{\rm OUT}$  or  $T_{\rm J}$ .  $^2$ Measured on a typical two-sided PCB with 2 in. $^2$  copper ground plane.

<sup>3</sup>Measured on a JEDEC-standard "High-K" 4-layer PCB.

Designed for PWM (pulse width modulated) control of dc motors, the A3949 is capable of peak output currents to  $\pm 2.8$  A and operating voltages to 36 V.

PHASE and ENABLE input terminals are provided for use in controlling the speed and direction of a dc motor with externally applied PWM control signals. Internal synchronous rectification control circuitry is provided to reduce power dissipation during PWM operation.

Internal circuit protection includes thermal shutdown with hysteresis, undervoltage monitoring of  $V_{\rm BB}$  and  $V_{\rm CP}$ , and crossover current protection

The A3949 is supplied in a choice of two power packages, a 16-pin plastic SOIC with a copper batwing tab (part number suffix *LB*), and a low profile (1.1mm) 16-pin TSSOP (suffix *LP*) with exposed power tab. Both packages are available in a lead-free version (100% matte tin leadframe).

### **FEATURES**

- Single supply operation
- Very small outline package
- Low  $R_{DS(ON)}$  outputs
- Sleep function
- Internal UVLO
- Crossover current protection
- Thermal shutdown protection

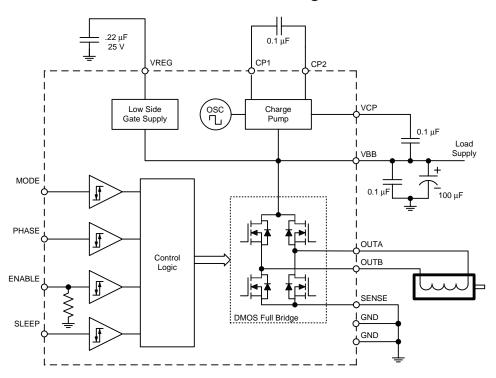
Use the following complete part numbers when ordering:

Part Number	Pb-free*	Package	Packing		
A3949SLB-T	A3949SLB-T Yes		47 per tube		
A3949SLBTR-T	Yes	16-pin, SOIC	1000 per reel		
A3949SLP-T	A3949SLP-T Yes		96 per tube		
A3949SLPTR-T	Yes	16-pin, TSSOP	4000 per reel		

Pb-based variants are being phased out of the product line. The variants cited in this footnote are in production but have been determined to be LAST TIME BUY. This classification indicates that sale of this device is currently restricted to existing customer applications. The variants should not be purchased for new design applications because obsolescence in the near future is probable. Samples are no longer available. Status change: October 31, 2006. Deadline for receipt of LAST TIME BUY orders: April 27, 2007. These variants include: A3949SLB, A3949SLBTR, A3949SLPTR.



## Functional Block Diagram



## Control Logic Table

PHASE	ENABLE	MODE	SLEEP	OUTA	OUTB	Function
1	1	Х	1	Н	L	Forward
0	1	Х	1	L	Н	Reverse
Х	0	1	1	L	L	Brake (slow decay)
1	0	0	1	L	Н	Fast decay SR*
0	0	0	1	Н	L	Fast decay SR*
Х	Х	Х	0	Hi-Z	Hi-Z	Sleep mode

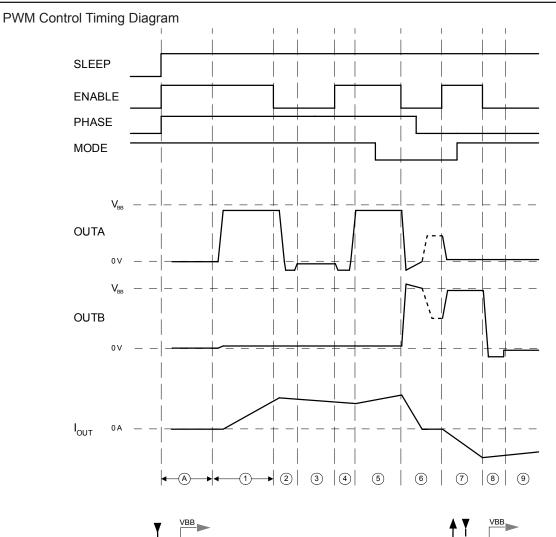
<sup>\*</sup> To prevent reversal of current during fast decay SR (synchronous rectification), the outputs go to the high impedance state as the current approaches zero.

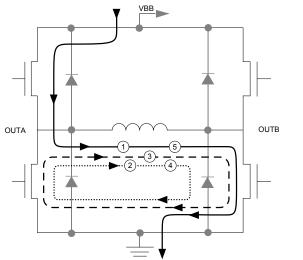


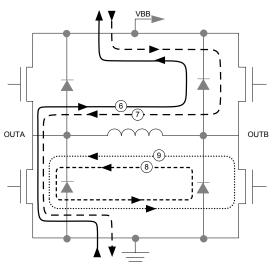
## **ELECTRICAL CHARACTERISTICS** at $T_A$ = 25°C, $V_{BB}$ = 8 V to 36 V (unless otherwise noted)

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
		Source driver, $I_{OUT} = -2.8 \text{ A}$ , $T_{J} = 25^{\circ}\text{C}$	_	.4	.48	Ω
Source driver, $I_{OUT} = -2.8  A$ , $T_j = 25^{\circ} C$ — Source driver, $I_{OUT} = -2.8  A$ , $T_j = 125^{\circ} C$ — Source driver, $I_{OUT} = -2.8  A$ , $T_j = 125^{\circ} C$ — Sink driver, $I_{OUT} = -2.8  A$ , $T_j = 125^{\circ} C$ — Sink driver, $I_{OUT} = -2.8  A$ , $T_j = 125^{\circ} C$ — Sink driver, $I_{OUT} = -2.8  A$ , $T_j = 125^{\circ} C$ — Source diode, $I_F = -2.8  A$ — Sink diode, $I_F = -2.8  A$ — Sink diode, $I_F = -2.8  A$ — Charge pump turned on; outputs disabled — Sleep mode — Sleep — Sle	_	.68	_	Ω		
Output-On Resistance	R <sub>DSON</sub>	Sink driver, I <sub>OUT</sub> = 2.8 A, T <sub>J</sub> = 25°C	_	.3	.43	Ω
		Sink driver, $I_{OUT} = -2.8 \text{ A}$ , $T_J = 125^{\circ}\text{C}$	-	.576	_	Ω
Rady Diada Farward Valtage	V	Source diode, I <sub>F</sub> = -2.8 A	_	1.1	1.3	V
Body Diode Forward Voltage	v <sub>F</sub>	Sink diode, I <sub>F</sub> = 2.8 A	_	1	1.3	V
		f <sub>PWM</sub> < 50 kHz	_	6	8.5	mA
Motor Supply Current	l <sub>BB</sub>	Charge pump turned on; outputs disabled	_	3	4.5	mA
		Sleep mode	- - - - - - 2.0 - 2.7 - - - -	_	10	μΑ
Logic Input Voltage	V <sub>IN(1)</sub>		2.0	_	_	V
PHASE, ENABLE, MODE			_	_	0.8	V
Logic Input Voltage	V <sub>IN(1)</sub>		2.7	_	_	V
SLEEP				_	0.8	V
Logic Input Current		V <sub>IN</sub> = 2.0 V	_	< 1.0	20	μΑ
PHASE, MODE pins	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	ı	< -2.0	-20	μΑ
Logic Input Current	I <sub>IN(1)</sub>	V <sub>IN</sub> = 2.0 V	_	40	100	μΑ
ENABLE pin	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	16	40	μΑ
Logic Input Current		V <sub>IN</sub> = 2.7 V	_	27	50	μΑ
SLEEP pin	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	< 1	10	μΑ
Drong setion Delay Times	4	From PWM change to source or sink turn on	_	600	_	ns
Propagation Delay Times	$t_{\sf pd}$	From PWM change to source or sink turn off	_	100	_	ns
Crossover Delay	t <sub>COD</sub>		_	500	_	ns
Protection Circuitry						
UVLO Enable Threshold		VBB rising	_	6	_	V
UVLO Hysteresis			_	250	_	mV
Thermal Shutdown Temp.	$T_{J}$		_	170	_	°C
Thermal Shutdown Hysteresis	$\Delta T_{_{ m J}}$		_	15	_	°C









Charge pump and VREG power-up delay (approximately 200 us)



## **Functional Description**

**VREG.** This supply voltage is used to operate the sinkside DMOS outputs. VREG is internally monitored and in the case of a fault condition, the outputs of the device are disabled. The VREG pin should be decoupled with a  $0.22 \mu F$ capacitor to ground.

**Charge Pump.** The charge pump is used to generate a supply above VBB to drive the source-side DMOS gates. A 0.1 uF ceramic monolithic capacitor should be connected between CP1 and CP2 for pumping purposes. A 0.1 uF ceramic monolithic capacitor should be connected between VCP and VBB to act as a reservoir to run the high side DMOS devices. The VCP voltage is internally monitored, and in the case of a fault condition, the outputs of the device are disabled.

**Shutdown.** In the event of a fault due to excessive junction temperature, or low voltage on VCP or VREG, the outputs of the device are disabled until the fault condition is removed. At power-up, the UVLO circuit disables the drivers.

**Sleep Mode.** Control input SLEEP is used to minimize power consumption when the A3949 is not in use. This disables much of the internal circuitry, including the low-side gate supply and the charge pump. A logic low on this pin puts the device into Sleep mode. A logic high allows normal operation. After coming out of Sleep mode, the user should wait 1 ms before applying PWM signals, to allow the charge pump to stabilize.

**Braking.** The braking function is implemented by driving the device in slow decay mode via the MODE pin, and applying an enable chop command. Because it is possible to drive current in both directions through the DMOS switches, this configuration effectively shorts out the motor-generated BEMF, as long as the enable chop mode is asserted on the ENABLE pin. The maximum current can be approximated by V<sub>REME</sub> / R<sub>I</sub>. Care should be taken to insure that the maximum ratings of the device are not exceeded in worse case braking situations of high speed and high inertial loads.



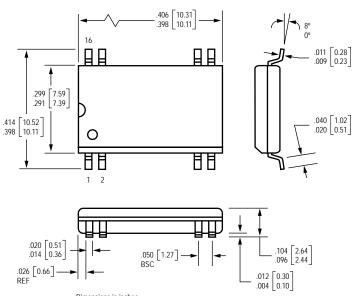
### Terminal List Table

Nome	B	Nun	Number			
Name	Description	TSSOP-16	SOIC-16			
N/C	Not used	1	1			
MODE	Logic input	2	2			
PHASE	Logic input for direction control	3	3			
GND	Ground	4*	4*			
SLEEP	Logic input	5	5			
ENABLE	Logic input	6	6			
OUTA	Output A for full bridge	7	7			
SENSE	Power return	8	8			
VBB	Load supply voltage	9	9			
OUTB	Output B for full bridge	10	10			
CP1	Charge pump capacitor	11	11			
CP2	Charge pump capacitor	12	12			
GND	Ground	13*	13*			
VCP	Reservoir capacitor	14	14			
VREG	Low side gate supply decoupler	15	15			
N/C	Not used	16	16			

<sup>\*</sup>For the TSSOP package, connect pins 4 and 13 to the exposed thermal pad via the PCB layout. In the SOIC package, the pins are internally connected.



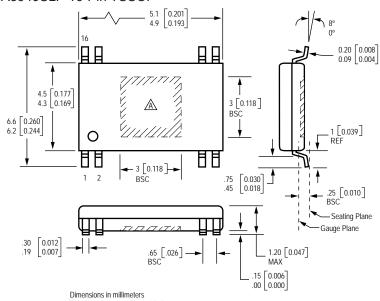
### A3949SLB 16-Pin Batwing SOIC



Dimensions in inches Metric dimensions (mm) in brackets, for reference only

Leads 4 and 13 are connected inside the device package.

### A3949SLP 16-Pin TSSOP



U.S. Customary dimensions (in.) in brackets, for reference only A Exposed thermal pad (bottom surface)

No internal connection of leads for thermal dissipation.

### NOTES:

- 1. Exact body and lead configuration at vendor's option within limits shown.
- 2. Lead spacing tolerance is non-cumulative.



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